

Description

The ASM05 is an uni-directional TVS diode array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting sensitive semiconductor components from damage. The ASM05 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a lead-free SOT-23 package. It is designed to protect components which are connected to data and transmission lines from voltage surges.

Features

- 320W peak pulse power (8/20µs)
- Protects one two uni-directional line(s)
- Ultra low leakage: nA level
- Operating voltage: 5V
- Low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±30kV
 Contact discharge: ±30kV
 - IEC61000-4-5 (Lightning) 23A (8/20µs)
- RoHS Compliant

Mechanical Characteristics

Package: SOT-23Lead Finish: Matte Tin

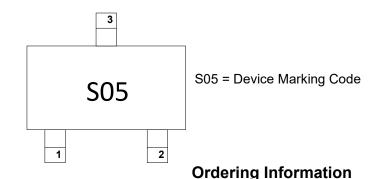
Case Material: "Green" Molding Compound.Terminal Connections: See Diagram Below

Marking Information: See Below

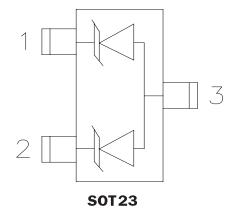
Applications

- Peripherals
- Industrial Equipment
- Notebook Computers
- Portable Instrumentation
- Microprocessor Based Equipment
- Cell Phone Handsets and Accessories
- Personal Digital Assistants (PDAs) and Pagers

Marking Information



Dimensions and Pin Configuration



Circuit and Pin Schematic

Part Number	umber Packaging Reel	
ASM05	3000/Tape & Reel	7 inch

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Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

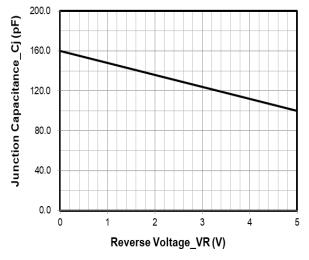
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	320	W
Peak Pulse Current (8/20µs)	IPP	23	Α
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	±30 ±30	kV
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

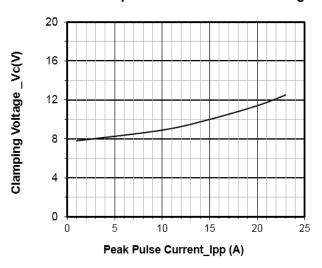
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Reverse Breakdown Voltage	VBR	6			V	IT = 1mA
Reverse Leakage Current	I _R			0.5	μA	VRWM = 5V, any I/O pin to ground
Clamping Voltage	Vc			8	V	IPP = 1A (8 x 20μs pulse), any I/O pin to ground
Clamping Voltage	Vc			14	V	IPP = 23A (8 x 20µs pulse), any I/ O pin to ground
Junction Capacitance	Сл		160		pF	VR = 0V, f = 1MHz, any I/O pin to ground



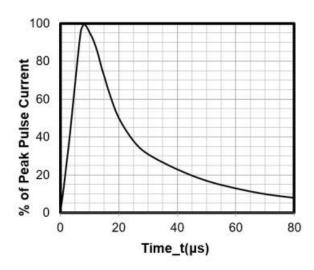
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



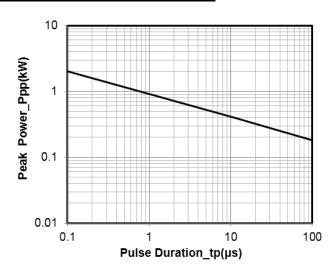
Junction Capacitance vs. Reverse Voltage



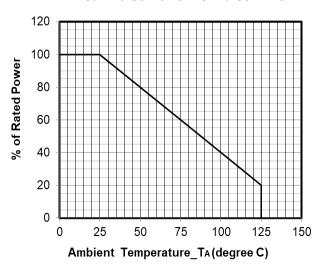
Clamping Voltage vs. Peak Pulse Current



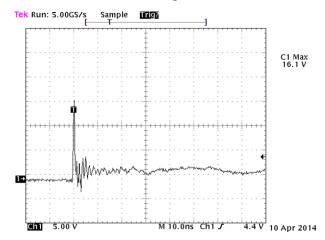
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



Power Derating Curve



Note: Data is taken with a 10x attenuator

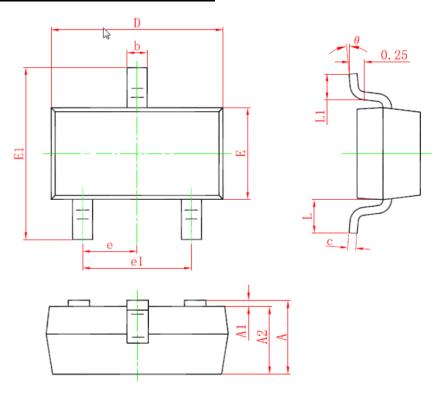
ESD Clamping Voltage

8 kV Contact per IEC61000-4-2

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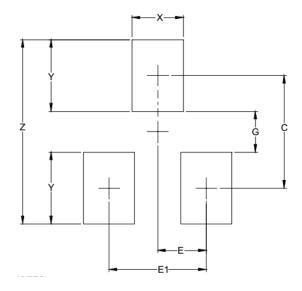
SOT-23 Package Outline Drawing



	DIMENSIONS					
	MILLIMETERS			INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90		1.15	0.035		0.045
A1	0.00		0.10	0.000		0.004
A2	0.90		1.05	0.035		0.041
b	0.30		0.50	0.012		0.020
С	0.08		0.15	0.003		0.006
D	2.80		3.00	0.110		0.118
Е	1.20		1.40	0.047		0.055
E1	2.25		2.55	0.089		0.100
е	0.95TYP			0.037TYP		
e1	1.80		2.00	0.071		0.079
L	0.55REF			0.022REF		
L1	0.30		0.50	0.012		0.020
Θ	0°		8°	0°		8°



Suggested Land Pattern



0)/84	DIMENSIONS			
SYM	INCHES	MILLIMETERS		
С	.087	2.20		
Е	.037	0.95		
E1	.075	1.90		
G	.031	0.80		
Х	.039	1.00		
Υ	.055	1.40		
Z	.141	3.60		

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